Semiconductor Device Set - Page 1 of 1



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Inclosure N	Naterial:
Metal all tra	nsistor
Overall Ler	ngth:
0.190 inche	s all transistor
Terminal Lo	ength:
1.500 inche	s all transistor
Overall Dia	meter:
0.209 inche	s all transistor
Internal Co	nfiguration:
Junction cor	ntact all transistor
Internal Jui	nction Configuration:
Pnp all trans	sistor
Componen	t Function Relationship:
Matched	
Componen	t Name And Quantity:
2 transistor	
Mounting M	Nethod:
Terminal all	transistor
Terminal C	ircle Diameter:
0.100 inche	s all transistor
Semicondu	ictor Material:
Silicon all tra	ansistor
Voltage Ra	ting In Volts Per Characteristic:
25.0 emitte	r to base voltage, dc all transistor and 30.0 collector to base voltage, dc all transisto
Current Ra	ting Per Characteristic:
10.00 milliai	mperes source cutoff current all transistor
Special Fea	atures:
Double emit	tter
Terminal Ty	ype And Quantity:
4 uninsulate	ed wire lead all transistor
Shelf Life:	
N/a	
Unit Of Mea	asure:
Demilitariza	ation:
No	
Fiig:	
-	